Temperature coefficients and LeTID of bifacial PV modules









BifiPV workshop Amsterdam – September 2019



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Two topics with Yield impact for Bifacial PV











Two topics with Yield impact for Bifacial PV











Temperature coefficients are a big challenge for the PV industry



Round robin between 12 leading laboratories:

Typical tempco measurement uncertainties **OVER** 10%

[1] MIHAYLOV, B.V. ... et al, 2014. Results of the Sophia module intercomparison part-1: STC, low irradiance conditions and temperature coefficients - C-Si technologies



This uncertainty gets little attention, but impact can be significant



In sunbelt area's with high operating temperatures, the impact is largests

A 10% difference in temperature coefficient equates to a >1% difference in energy yield

The following figure shows the relationship between temperature coefficient and relative energy yield for the specified location (Phoenix, USA) [2]:

10% difference in temperature coefficient = 1.2% difference in energy yield for this PV plant location

Image adjusted from : [2] Yang Yang, YingBin Zhang...Pierre J. Verlinden, 2014. Understanding the uncertainties in the measurement of temperature coefficients of Si PV modules – PVSyst modelling of energy yield with varying temperature coefficient in Phoenix, USA climatic conditions

Our Goal:

Reduce T.C. measurement uncertainty from >10% to <5%, for all PV technologies

The single side and flip method is now regarded as most accurate

Bifacial measurements in the temperature controlled lab flasher: very low rear irradiance

IEC 60904-1-2

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Result: on all 9 points rear side irradiance < 3W/m²

Voltage measured [mV]

Position on		
module rear	95.35	1000
P1	0.215	2.25
P2	0.192	2.01
Р3	0.247	2.59
P4	0.144	1.51
Р5	0.108	1.13
Р6	0.157	1.65
P7	0.161	1.69
Р8	0.169	1.77
Р9	0.176	1.85

The temperature box is suitable for bifacial module testing according to IEC 60904-1-2 in combination with module mask

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Irradiance equivalent [W/m²]

Pulsewidth: HJT modules require a pulse up to 300 ms

HJT: 100-300 ms

Pmax deviation as a function of sweep lenght and sweep direction

- Every cell V_{oc} increase of 18mV roughly doubles the carrier concentration, which causes a doubled sweep time effect ^[2]
- More cells in series (e.g. 60 to 72 cells) reduces the string capacitance
- Multiflash can be applied in combination with Single Long pulse

[1] Source: Based on 5600 SLP sweep time sequence measurement of PERC module (2016)

[2] Source: Smets et al., Solar Energy: the physics and engineering of photovoltaic conversion technologies and systems (2016)

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Pulsewidth: a stable single long pulse enables lowest uncertainty on high efficiency PV technologies

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Spectrum: a wide, 300-1200 nm spectrum is critical for T.C. measurement on high efficiency cell technology

Image adjusted from: Zhang et al.: 335-W World-record p-type monocrystalline module IEEE journal of photovoltaics, VOL. 6, NO. 1 (2016)

Spectrum: when temperature increases, QE changes in 1000-1200 nm

Source: PTB Photoclass

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Spectral coverage of >99% in 300-1200 nm of Eternalsun Spires 5100 & 5600 SLP Flashers enable the lowest uncertainty

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				AM	1.5 G		Spire Flas	sher solar sin	nulator	<u>Results</u>
	AM1 5	\$86-0003	8	nm	Value	nm	Value	Midpoint	Value	SPC
2,5	- AWI1.5	380-0003	0	300.0	0.0010	300	0.005	300.5	0.0052	99.31%
				300.5	0.0012	301	0.006	301.5	0.0059	
2,0	^			301.0	0.0019	302	0.006	302.5	0.0066	SPD
		0 M M	~	301.5	0.0027	303	0.007	303.5	0.0072	34.65%
1,5		. K. have	₩¥	302.0	0.0029	304	0.008	304.5	0.0079	
1.0	MAN			302.5	0.0043	305	0.008	305.5	0.0092	
1,0				303.0	0.0071	306	0.010	306.5	0.0110	
0,5	<u>x</u> 117			303.5	0.0090	307	0.012	307.5	0.0128	Edition 2
				304.0	0.0095	308	0.014	308.5	0.0146	Edition 3
0,0				304.5	0.0120	309	0.016	309.5	0.0164	
300	400	500	600	305.0	0.0165	310	0.017	310.5	0.0190	

Eternalsun Spire flashers have spectrum coverage starting at 300nm. This is critical for accurately measuring high efficiency technologies

Temperature control box added to flasher:

- Heating and cooling from 15 C to 85 C
- Temperature control chamber moves down to fully enclose PV module for accurate temperature control

Temperat

ure

Temperature control: temperature uniformity directly affects uncertainty

Any temperature difference between individual cells in the module causes an error in the coefficient

Temperat ure

The "stable temperatures/dwell" method reduces uncertainty and is therefore recommended by IEC

"At each temperature level of interest, the module temperature should be **stable**"

True cell temperature stability is ensured by continuously monitoring Voc

IV performance is determined by the true, internal solar cell temperature, which often differs from the temperature of the backside of the module that is measured.

Module V_{oc} at temperatures from 85°C to 10°C in steps of 15°C

The error caused by measurement during natural cooldown can be up to 7%

Natural cooldown method

Results: significant differences between PV technologies

Source: Eternalsun Spire temperature coefficients study on 20 different PV modules, using Temperature Controlled Lab Flasher and HPLS for CdTe

Results: behavior is not always linear and the T.C. dependent on the range of interest

Source: Eternalsun Spire temperature coefficients study on 11 different PV modules, using Temperature Controlled Lab Flasher

Results: front and rear temperature coefficients can differ significantly

LeTID & LID: the difference

	LID	LeTID
Expected cause	Boron-Oxygen complexes or metal defects	Diffusing (moving) Hydrogen
Mitigation	Add hydrogen	Less hydrogen or temperature treatment
Timescale of effect	10-20 hours	50-500 hours
Temperatures	25-50 °C	60-90 °C
Potential extent of effect	0-3% reported c-Si modules	0-8% reported c-Si modules (commercial)

[1] Chan, Catherine et al. (2017). Modulation of Carrier-Induced Defect Kinetics in Multi-Crystalline Silicon PERC Cells Through Dark Annealing. Solar RRL [2] Wenham, Stuart (2016). UNSW Advanced Hydrogenation. SPREE Alumni Event presentation. 8th December, 2016

Setup used for LeTID study

- 1 sun Class AAA+ illumination
- 300 to 1200 nm spectrum
- 2 modules simultaneously

- 20 °C to 100 °C module temperature
- In-situ IV measurements
- Custom IV setpoints (e.g. Mpp) between IV

Setup

LeTID: visibility in EL imaging

LeTID - Eternalsun Spire Whitepaper - May 2019

Alternative procedure: current soaking and interval IV flashing

Procedure: Benefit of in-situ IV vs current soaking and flashing

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LeTID Results

LeTID test at 85C, Mpp between in-situ IV's

Source: Eternalsun Spire LeTID study on 14 different PV modules, using High Performance Light Soaker

LeTID Results

Source: Eternalsun Spire LeTID study on 14 different PV modules, using High Performance Light Soaker

Thank you!

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A+A+A+ 270ms Sun Simulators Advanced Temperature control

IV and EL test services at Rotterdam harbour warehouse

